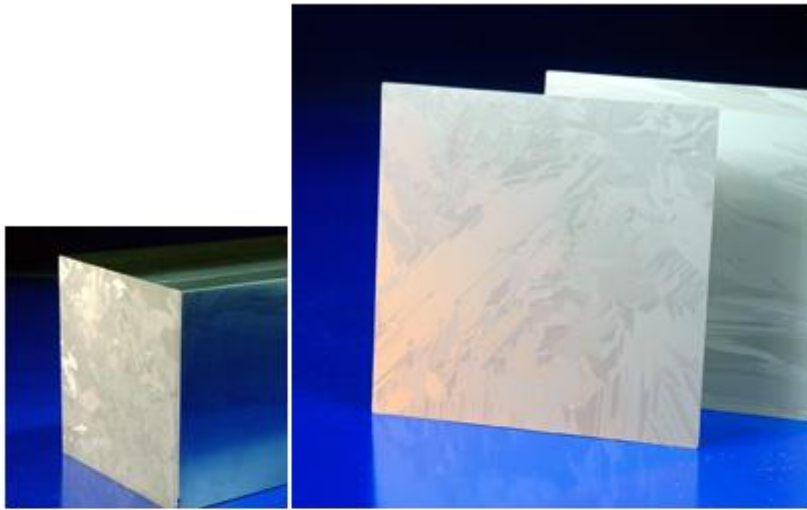


## High Efficiency Multi Crystalline Wafer

High Efficiency Multi Wafers have set a model for top quality multi wafers. The leading process techniques and rigorous wafer inspection system ensure that its electrical output remains in the highest criterion. High Efficiency Multi Wafers are our major product and have been adopted constantly by most first-tier cell manufacturers around the world.



**156\*156 Multi-wafer**

	<b>General Spec.</b>	<b>Unit</b>
Square Length	156+/-0.5	mm
Bevel Width	0.5-2	mm
Ingot Growing Method	DS	
Dopant Type	Boron	
Conductivity	P	
Resistivity	0.5-3	Ohm.cm
Thickness	180+/-20, 200+/-20	um